

Fig. 1A

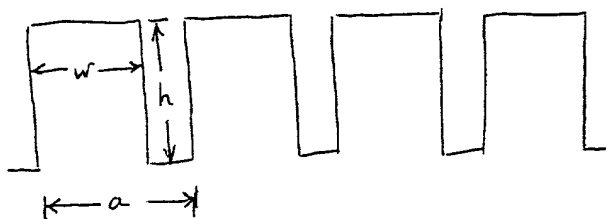


Fig. 1B

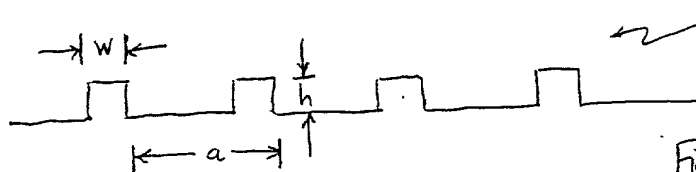


Fig. 1C

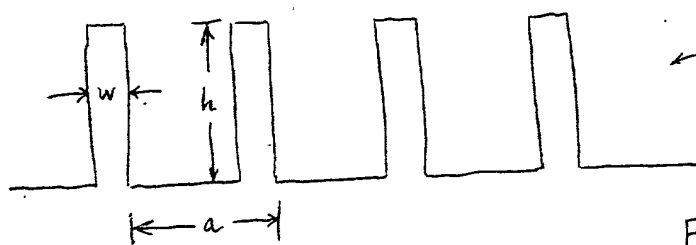


Fig. 1D

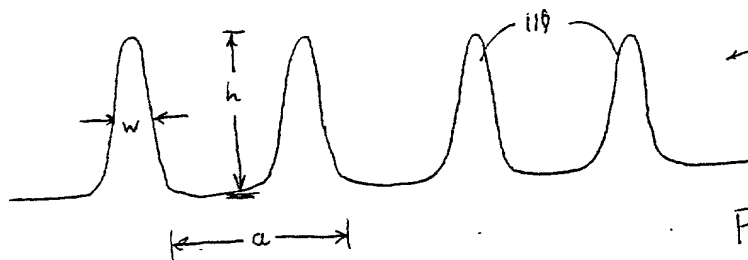


Fig. 1E

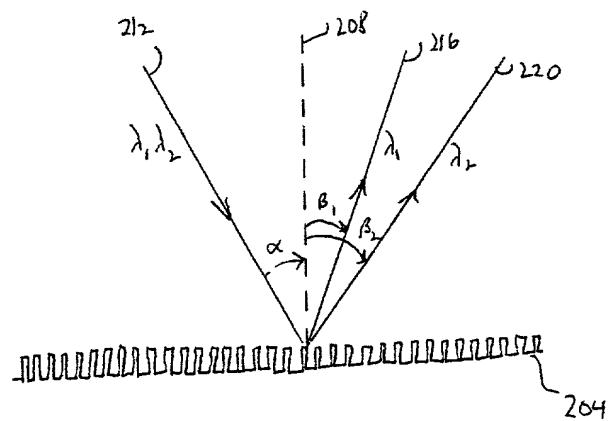


Fig. 2

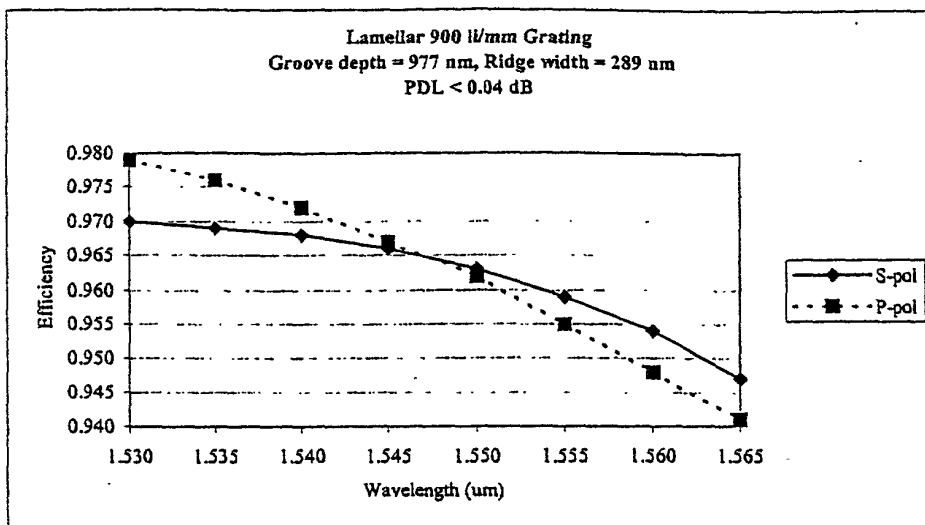


Fig. 3A

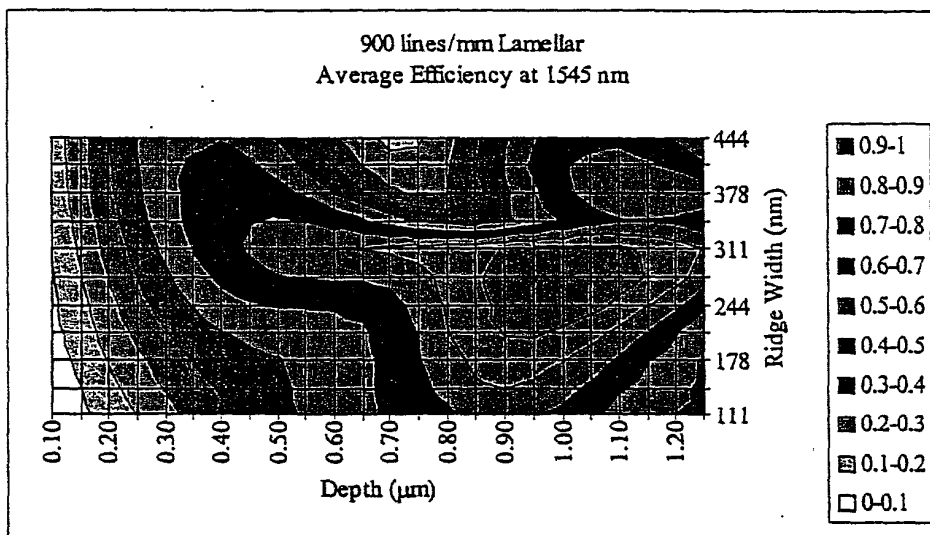


Fig. 3B

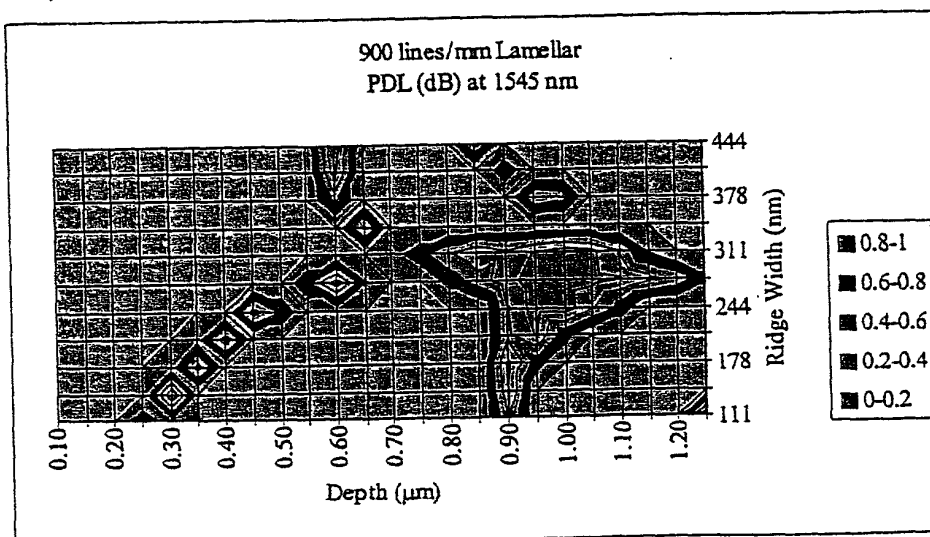


Fig. 3C

FIG. 4A

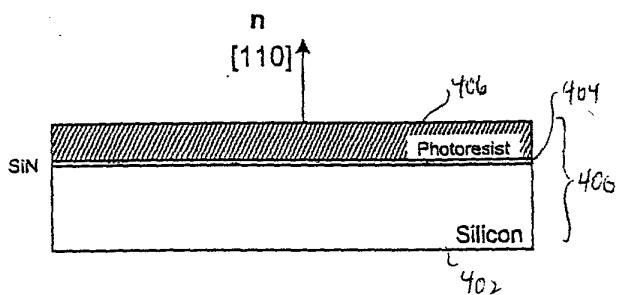


Fig. 4A

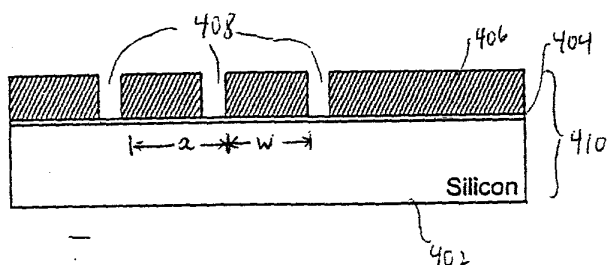
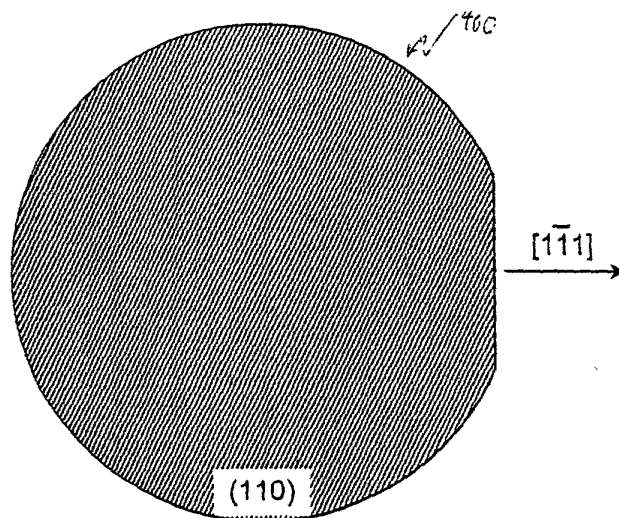


Fig. 4B

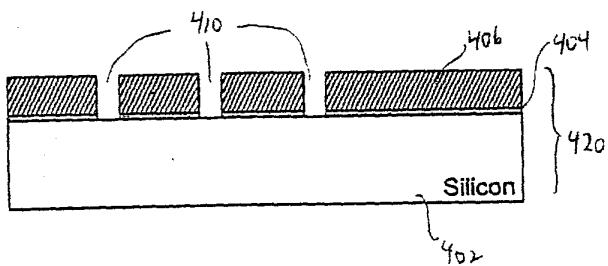
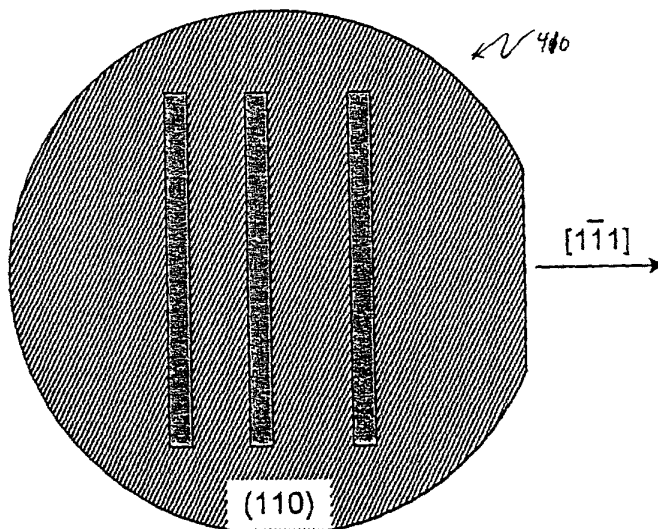
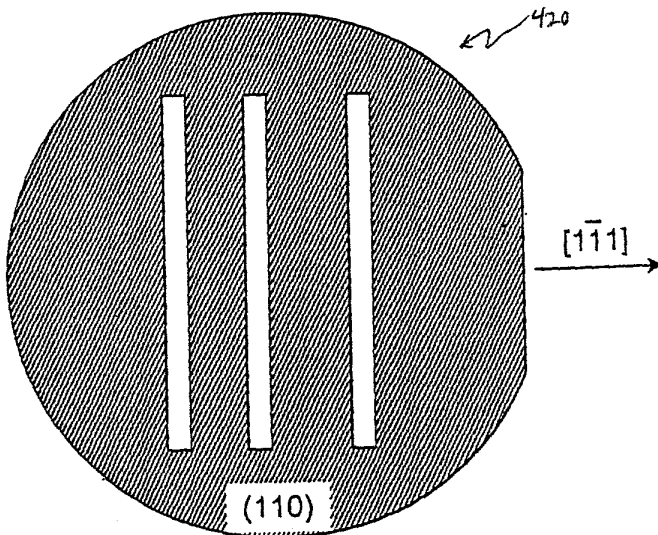


Fig. 4C



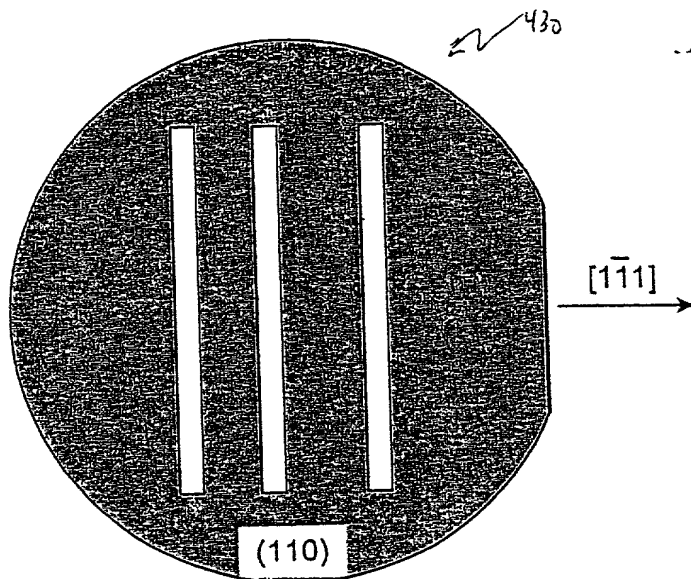
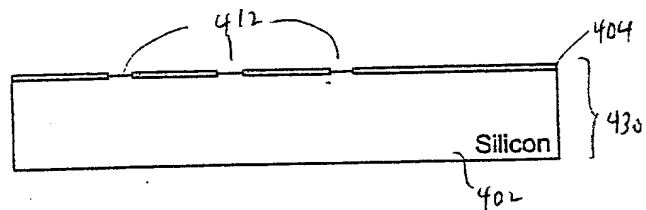


Fig. 4D

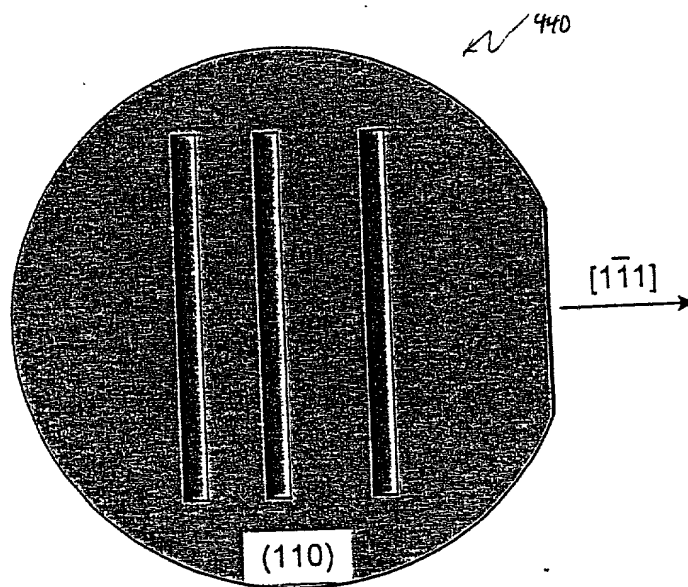
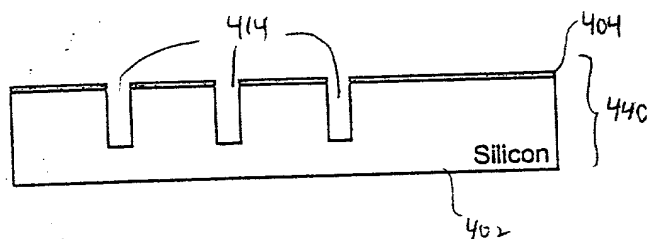


Fig. 4E

Figure 1 is a schematic diagram of a device 450. The top portion is a top view showing a circular region 450 containing a series of vertical bars. The width of each bar is labeled 'a' and the spacing between bars is labeled 'w'. A dashed line AA-AA' passes through the center. A crystallographic direction $[1\bar{1}1]$ is indicated by an arrow. The bottom portion is a cross-sectional view AA-AA' showing a substrate 450 with a series of rectangular features. The height of these features is labeled 'n' and the width is labeled 'w'. The substrate is labeled (110).

Fig 4F

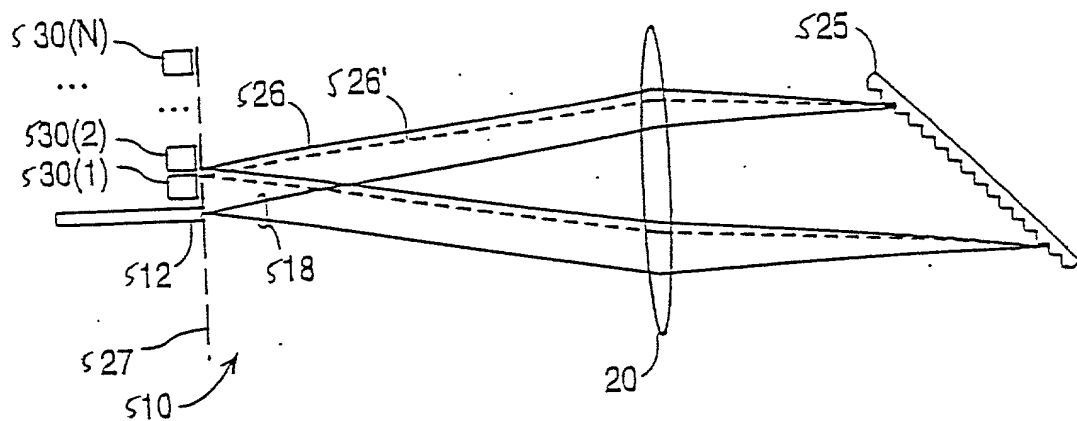


FIG. 5A

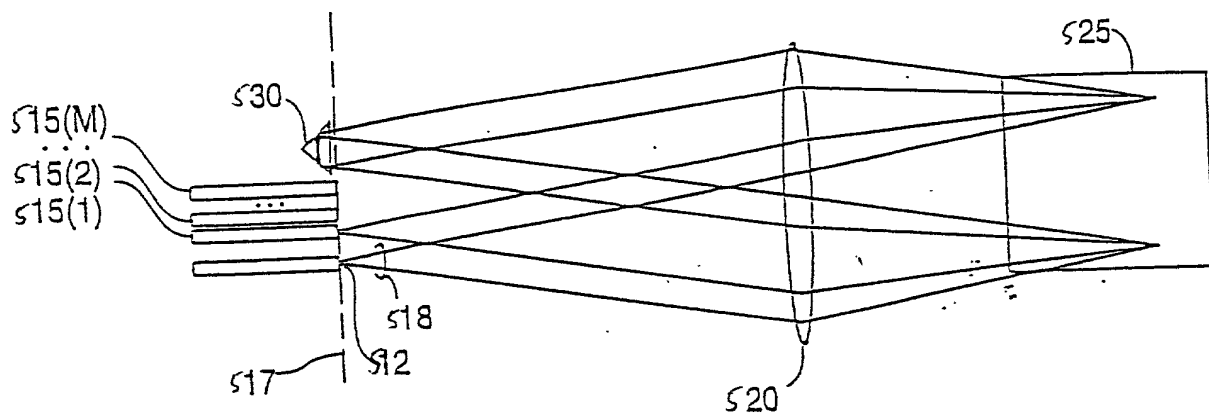


FIG. 5B

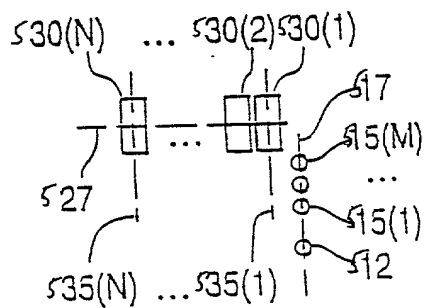


FIG. 5C